ESD-Protection Diode in SOD923

Features

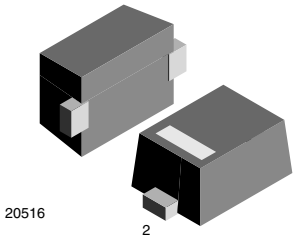
- Single-line ESD-protection device
- Reverse working range = 12 V
- ESD-immunity acc. IEC 61000-4-2
  - > 30 kV contact discharge
  - > 30 kV air discharge
- Tiny SOD923 package
- Package height = 0.4 mm
- Typ. capacitance 12.5 pF (V_R = 6 V; f = 1 MHz)
- Leakage current < 0.1 µA (V_R = 12 V)
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

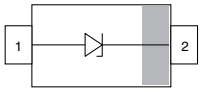
Pb-free

e3

RoHS COMPLIANT

GREEN (5-2008)*





Marking (example only)

Bar = Cathode marking
X = Date code
Y = Type code (see table below)

Ordering Information

Device name	Ordering code	Taped units per reel (8 mm tape on 7" reel)	Minimum order quantity
VESD12A1C-02Z	VESD12A1C-02Z-GS08	8000	8000

Package Data

Device name	Package name	Type code	Weight	Molding compound flammability rating	Moisture sensitivity level	Soldering conditions
VESD12A1C-02Z	SOD923	E	0.45 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

Absolute Maximum Ratings

Rating	Test condition	Symbol	Value	Unit
Peak pulse current	acc. IEC 61000-4-5, t_P = 8/20 µs/single shot	I_{PPM}	4	A
Peak pulse power	acc. IEC 61000-4-5, t_P = 8/20 µs/single shot	P_{PP}	92	W
ESD immunity	contact discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV
	air discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV
Operating temperature	Junction temperature	T_J	- 40 to + 125	°C
Storage temperature		T_{STG}	- 55 to + 150	°C

* Please see document “Vishay Green and Halogen-Free Definitions (5-2008)” http://www.vishay.com/doc?99902

BiAs-Mode (Bidirectional Asymmetrical protection mode)

With the **VESD12A1C-02Z** one signal- or data-lines (L1) can be protected against voltage transients. With pin 1 connected to ground and pin 2 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified **M**aximum **R**everse **W**orking **V**oltage (V_{RWM}) the protection diode between data line and ground offers a high isolation to the ground line. The protection device behaves like an open switch.

As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The **C**lamping **V**oltage (V_C) is defined by the **BR**eakthrough **V**oltage (V_{BR}) level plus the voltage drop at the series impedance (resistance and inductance) of the protection device.

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low **F**orward **V**oltage (V_F) clamps the negative transient close to the ground level.

Due to the different clamping levels in forward and reverse direction the **VESD12A1C-02Z** clamping behaviour is **Bi**directional and **As**ymmetrical (**BiAs**).

Electrical Characteristics

Ratings at 25 °C, ambient temperature, unless otherwise specified

VESD12A1C-02Z

BiAs mode (between pin 1 and pin 2)

Parameter	Test conditions/remarks	Symbol	Min.	Typ.	Max.	Unit
Protection paths	number of lines which can be protected	N_{lines}			1	lines
Reverse stand-off voltage	at I_R = 0.1 µA	V_{RWM}	12			V
Reverse current	at V_R = 12 V	I_R		0.01	0.1	µA
Reverse break down voltage	at I_R = 1 mA	V_{BR}	13.5	14	16	V
Reverse clamping voltage	at I_{PP} = 1 A	V_C		15.8	17	V
	at $I_{PP} = I_{PPM}$ = 4 A	V_C		20	23	V
Forward clamping voltage	at I_{PP} = 0.2 A	V_F		0.9	1.2	V
	at I_{PP} = 1 A	V_F		1.1	1.5	V
	at $I_{PP} = I_{PPM}$ = 4 A	V_F		1.7	2.1	V
Capacitance	at V_R = 0 V; f = 1 MHz	C_D		30	36	pF
	at V_R = 6 V; f = 1 MHz	C_D		12.5		pF

Typical Characteristics

T_{amb} = 25 °C, unless otherwise specified

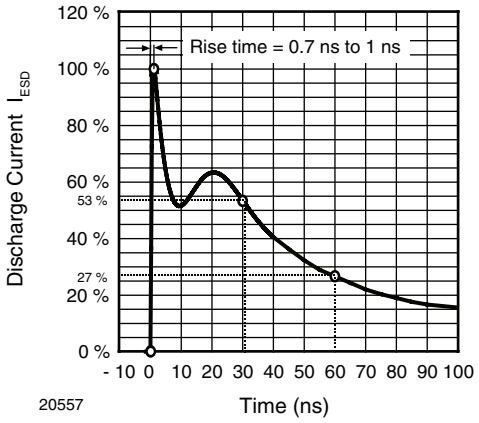


Figure 1. ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330 Ω/150 pF)

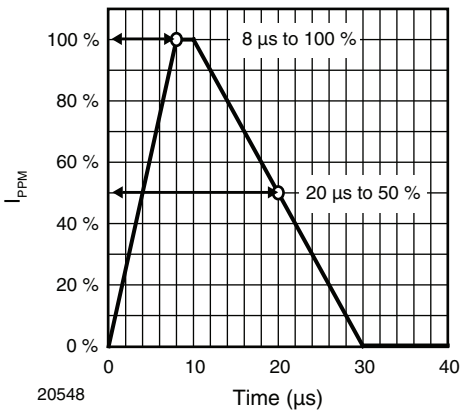


Figure 2. 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

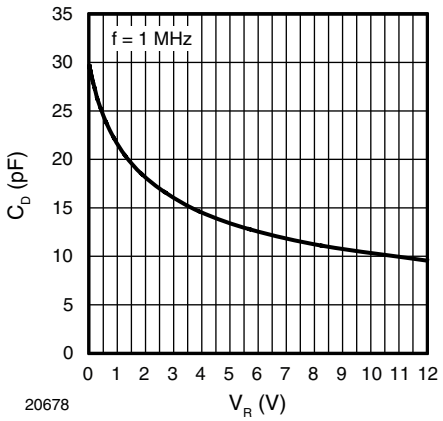


Figure 3. Typical Capacitance C_D vs. Reverse Voltage V_R

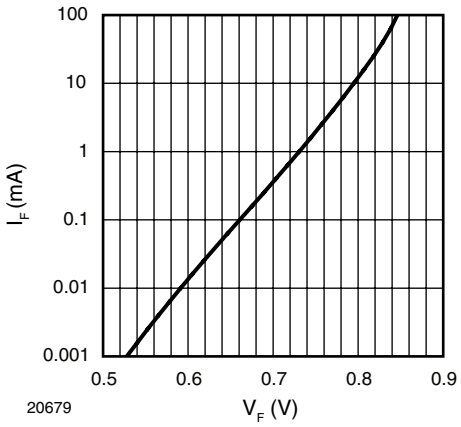


Figure 4. Typical Forward Current I_F vs. Forward Voltage V_F

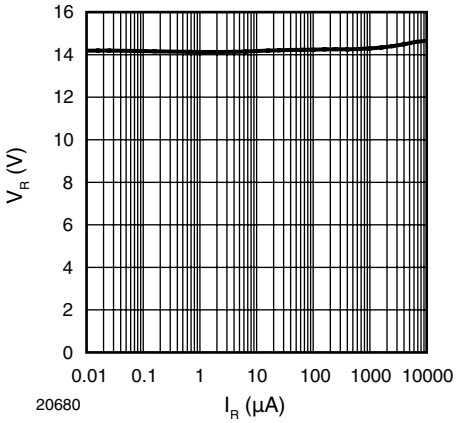


Figure 5. Typical Reverse Voltage V_R vs. Reverse Current I_R

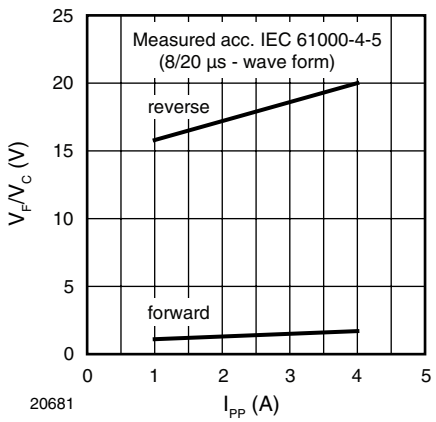


Figure 6. Typical Clamping Voltage vs. Peak Pulse Current I_{PP}

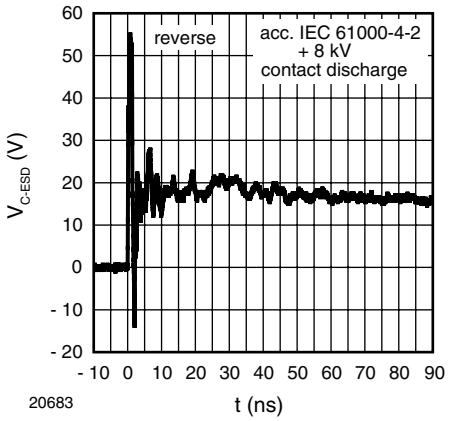


Figure 7. Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

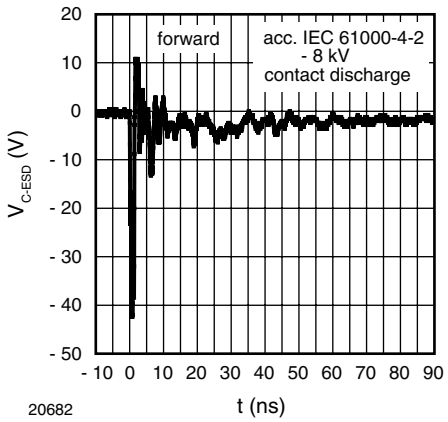


Figure 8. Typical Clamping Performance at - 8 kV Contact Discharge (acc. IEC 61000-4-2)

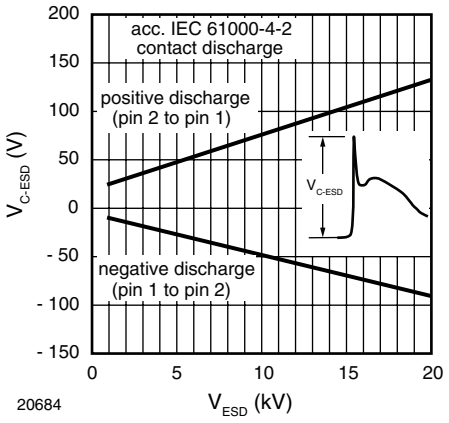
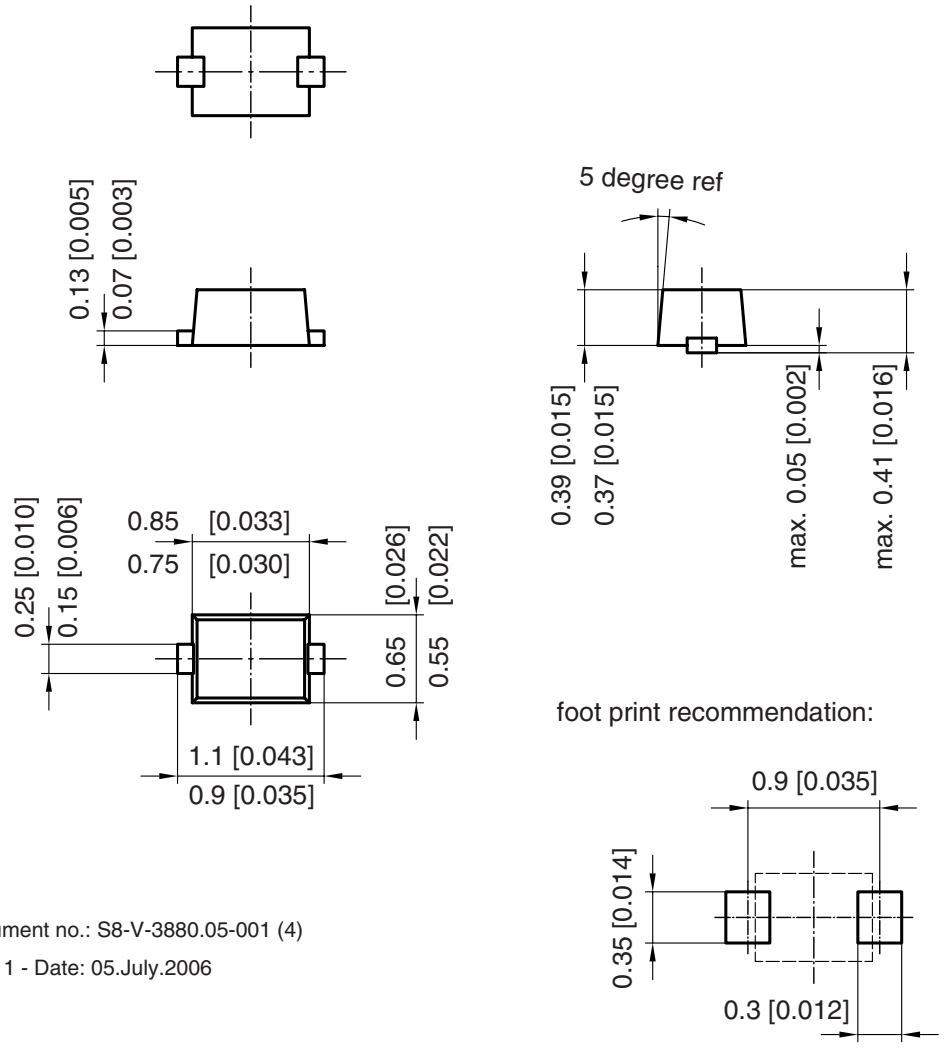


Figure 9. Typical Clamping Voltage at ± ESD Contact Discharge (acc. IEC 61000-4-2)

Package Dimensions in millimeters (inches): SOD923



Document no.: S8-V-3880.05-001 (4)

Rev. 1 - Date: 05.July.2006

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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

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